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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Volker Haerle
 Patent No. : 6,838,391 B2
 Issue Date : January 4, 2005
 Serial No. : 10/625,118
 Filed : July 22, 2003
 Title : METHOD OF SEMICONDUCTOR PROCESSING INCLUDING FLUORIDE

Art Unit : 2824
 Examiner : Beth E. Owens

Attn.: Certificate of Corrections Branch
 Commissioner for Patents
 P.O. Box 1450
 Alexandria, VA 22313-1450

REQUEST FOR CERTIFICATE OF CORRECTION

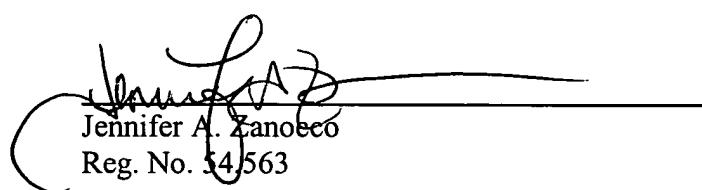
Applicant hereby requests that a certificate of correction be issued for the above patent in accordance with the attached request.

All errors sought to be corrected were made in printing by the Patent and Trademark Office, and no fee is believed to be due.

Please apply any unforeseen charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: March 7, 2005


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Certificate

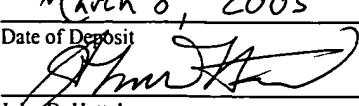
MAR 16 2005

of Correction

50264498.doc

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

March 8, 2005
 Date of Deposit

 John D. Hettel

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Only**UNITED STATES PATENT AND TRADEMARK OFFICE**
CERTIFICATE OF CORRECTION

PATENT NO. : 6,838,391 B2
DATED : JANUARY 4, 2005
INVENTOR(S) : VOLKER HÄRLE

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On Page 1, under OTHER PUBLICATIONS, reference B. Henle,;
Replace:

“*On Indium Phosphide & Rel. Materials, U.S. NY; IEEE, Bd.*”
with
-- *On Indium Phosphide & Rel. Materials, U.S. NY, IEEE, Bd.*--

On Page 2, under OTHER PUBLICATIONS, reference J.P. Harbison et al.,
Replace:

J.P. Harbison et al., “*Tungsten Patterning As A Technique*”
with
-- *J.P. Harbison et al., “Tungsten Patterning As A Technique*--

On Page 2, under OTHER PUBLICATIONS, reference JP 02-046407,
Replace:

“*JP 02-046407, Patent Abstracts of Japan, Veroffentlicung*:”
with
-- *JP 02-046407, Patent Abstracts of Japan, Veroffentlichung*--

MAILING ADDRESS OF SENDER:

PATENT NO. 6,838,391 B2

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DATED : JANUARY 4, 2005
INVENTOR(S) : VOLKER HÄRLE

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On Page 2, under OTHER PUBLICATIONS, reference Whidden T.K. et al.;

Replace:

“Whidden T.K. et al.; “*Catalyzed HF Vapor Etching Of*”
with

--Whidden T.K. et al.; “*Catalyzed HF Vapor Etching Of*--

On Page 2, under OTHER PUBLICATIONS, reference Wong M. et al.,;

Replace:

“*Oxide And Oxide Etching Using Vapor-Phase Hydrgoen*”
with

--*Oxide And Oxide Etching Using Vapor-Phase Hydrogen*--

In Column 5, at Line 29, in Claim 5,;

Replace:

“more from a group consisting of an underlying mask layer”
with

--or more from a group consisting of an underlying mask layer--

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PATENT NO. : 6,838,391 B2
DATED : JANUARY 4, 2005
INVENTOR(S) : VOLKER HÄRLE

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In Column 5, at Line 51, in Claim 7,;
Replace:
"defined an at least one (N+1)th semiconductor compo-"
with
--defined and at least one (N+1)th semiconductor compo---

In Column 6, at Line 29, in Claim 14,;
Replace:
"any remaining mask is moved by etching."
with
--any remaining mask is removed by etching.--

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